

512 K (32 K x 16) Static RAM

Features

- Pin-and function-compatible with CY7C1020CV33
- High speed
 - $t_{AA} = 10 \text{ ns}$
- Low active power
 - $I_{CC} = 60 \text{ mA @ } 10 \text{ ns}$
- Low CMOS standby power
 - $I_{SB2} = 3 \text{ mA}$
- 2.0 V Data retention
- Automatic power-down when deselected
- CMOS for optimum speed/power
- Independent control of upper and lower bits
- Available in Pb-free 44-pin 400-Mil wide Molded SOJ and 44-pin TSOP II packages

Functional Description

The CY7C1020DV33 is a high-performance CMOS static RAM organized as 32,768 words by 16 bits. This device has an automatic power-down feature that significantly reduces power consumption when deselected.

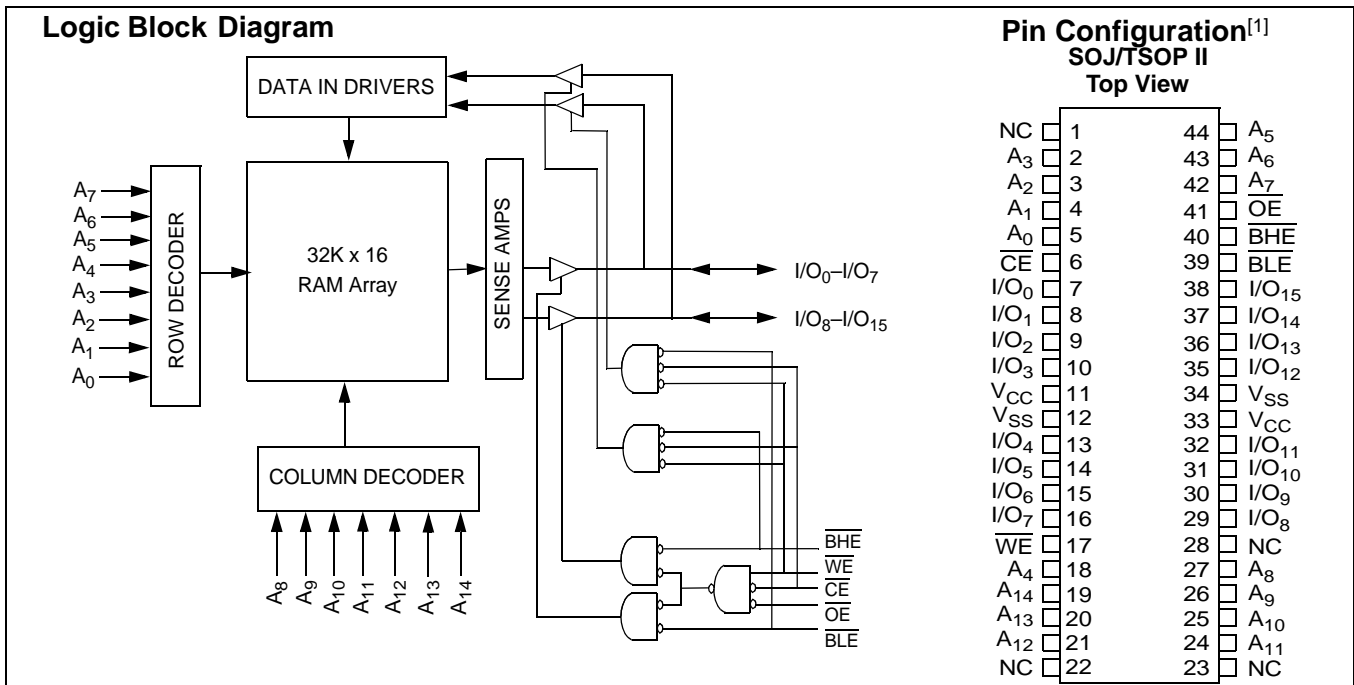
Writing to the device is accomplished by taking chip enable (\overline{CE}) and write enable (\overline{WE}) inputs LOW. If byte low enable (\overline{BLE}) is LOW, then data from I/O pins (I/O_0 through I/O_7), is written into the location specified on the address pins (A_0 through A_{14}). If byte high enable (\overline{BHE}) is LOW, then data from I/O pins (I/O_8 through I/O_{15}) is written into the location specified on the address pins (A_0 through A_{14}).

Reading from the device is accomplished by taking chip enable (\overline{CE}) and output enable (\overline{OE}) LOW while forcing the write enable (\overline{WE}) HIGH. If byte low enable (\overline{BLE}) is LOW, then data from the memory location specified by the address pins will appear on I/O_0 to I/O_7 . If byte high enable (\overline{BHE}) is LOW, then data from memory will appear on I/O_8 to I/O_{15} . See the truth table at the back of this data sheet for a complete description of read and write modes.

The input/output pins (I/O_0 through I/O_{15}) are placed in a high-impedance state when the device is deselected (\overline{CE} HIGH), the outputs are disabled (\overline{OE} HIGH), the \overline{BHE} and \overline{BLE} are disabled (\overline{BHE} , \overline{BLE} HIGH), or during a write operation (\overline{CE} LOW, and \overline{WE} LOW).

The CY7C1020DV33 is available in Pb-free 44-pin 400-Mil wide Molded SOJ and 44-pin TSOP II packages.

For a complete list of related documentation, [click here](#).



Notes

1. NC pins are not connected on the die.

Selection Guide

| | -10 (Industrial) | Unit |
|------------------------------|-------------------------|-------------|
| Maximum access time | 10 | ns |
| Maximum operating current | 60 | mA |
| Maximum CMOS standby current | 3 | mA |

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage temperature -65 °C to +150 °C

Ambient temperature with power applied -55 °C to +125 °C

Supply voltage on V_{CC} to Relative GND^[2] ... -0.5 V to +4.6 V

DC voltage applied to outputs in High-Z State^[2] -0.5 V to $V_{CC} + 0.5$ V

DC input voltage^[2] -0.5 V to $V_{CC} + 0.5$ V

Current into outputs (LOW) 20 mA

Static discharge voltage > 2001 V (per MIL-STD-883, Method 3015)

Latch-up current > 200 mA

Operating Range

| Range | Ambient Temperature | V_{CC} | Speed |
|------------|---------------------|---------------|-------|
| Industrial | -40 °C to +85 °C | 3.3 V ± 0.3 V | 10 ns |

Electrical Characteristics Over the Operating Range

| Parameter | Description | Test Conditions | -10 (Industrial) | | Unit |
|-----------|---|--|-------------------------|----------------|------|
| | | | Min. | Max. | |
| V_{OH} | Output HIGH voltage | $V_{CC} = \text{Min.}, I_{OH} = -4.0 \text{ mA}$ | 2.4 | | V |
| V_{OL} | Output LOW voltage | $V_{CC} = \text{Min.}, I_{OL} = 8.0 \text{ mA}$ | | 0.4 | V |
| V_{IH} | Input HIGH voltage | | 2.0 | $V_{CC} + 0.3$ | V |
| V_{IL} | Input LOW voltage ^[2] | | -0.3 | 0.8 | V |
| I_{IX} | Input Load current | $GND \leq V_I \leq V_{CC}$ | -1 | +1 | μA |
| I_{OZ} | Output leakage current | $GND \leq V_I \leq V_{CC}$, Output Disabled | -1 | +1 | μA |
| I_{CC} | V_{CC} operating supply current | $V_{CC} = \text{Max.}, I_{OUT} = 0 \text{ mA}, f = f_{MAX} = 1/t_{RC}$ | 100 MHz | 60 | mA |
| | | | 83 MHz | 55 | mA |
| | | | 66 MHz | 45 | mA |
| | | | 40 MHz | 30 | mA |
| I_{SB1} | Automatic CE Power-down Current—TTL Inputs | Max. V_{CC} , $\overline{CE} \geq V_{IH}$ $V_{IN} \geq V_{IH}$ or $V_{IN} \leq V_{IL}$, $f = f_{MAX}$ | | 10 | mA |
| I_{SB2} | Automatic CE Power-down Current—CMOS Inputs | Max. V_{CC} , $\overline{CE} \geq V_{CC} - 0.3 \text{ V}$, $V_{IN} \geq V_{CC} - 0.3 \text{ V}$, or $V_{IN} \leq 0.3 \text{ V}$, $f = 0$ | | 3 | mA |

Notes

- $V_{IL}(\text{min.}) = -2.0 \text{ V}$ and $V_{IH}(\text{max.}) = V_{CC} + 1 \text{ V}$ for pulse durations of less than 5 ns.

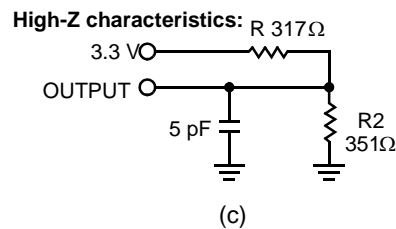
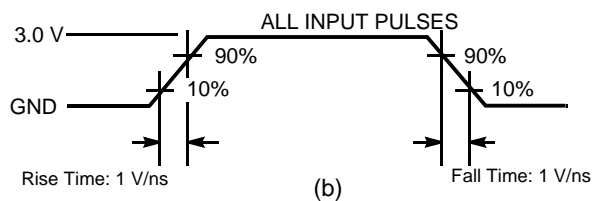
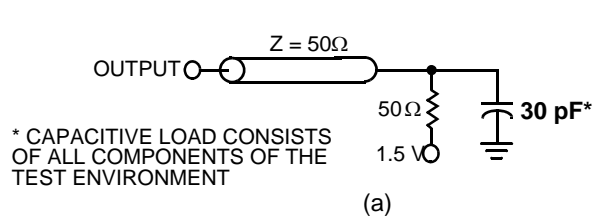
Capacitance^[3]

| Parameter | Description | Test Conditions | Max. | Unit |
|------------------|--------------------|---|------|------|
| C _{IN} | Input capacitance | T _A = 25°C, f = 1 MHz, V _{CC} = 3.3 V | 8 | pF |
| C _{OUT} | Output capacitance | | 8 | pF |

Thermal Resistance^[3]

| Parameter | Description | Test Conditions | SOJ | TSOP II | Unit |
|-----------------|--|---|-------|---------|------|
| Θ _{JA} | Thermal resistance (Junction to Ambient) | Still air, soldered on a 3 × 4.5 inch, four-layer printed circuit board | 59.52 | 53.91 | °C/W |
| Θ _{JC} | Thermal resistance (Junction to Case) | | 36.75 | 21.24 | °C/W |

AC Test Loads and Waveforms^[4]



Notes

- Tested initially and after any design or process changes that may affect these parameters.
- AC characteristics (except High-Z) are tested using the load conditions shown in Figure (a). High-Z characteristics are tested for all speeds using the test load shown in Figure (c).

Switching Characteristics Over the Operating Range ^[5]

| Parameter | Description | -10 (Industrial) | | Unit |
|---------------------------------------|--|------------------|------|---------|
| | | Min. | Max. | |
| Read Cycle | | | | |
| $t_{power}^{[6]}$ | V_{CC} (typical) to the first access | 100 | | μ S |
| t_{RC} | Read cycle time | 10 | | ns |
| t_{AA} | Address to data valid | | 10 | ns |
| t_{OHA} | Data Hold from Address Change | 3 | | ns |
| t_{ACE} | \overline{CE} LOW to data valid | | 10 | ns |
| t_{DOE} | \overline{OE} LOW to data valid | | 5 | ns |
| t_{LZOE} | \overline{OE} LOW to Low-Z ^[7] | 0 | | ns |
| t_{HZOE} | \overline{OE} HIGH to High-Z ^[7, 8] | | 5 | ns |
| t_{LZCE} | \overline{CE} LOW to Low-Z ^[7] | 3 | | ns |
| t_{HZCE} | \overline{CE} HIGH to High-Z ^[7, 8] | | 5 | ns |
| $t_{PU}^{[9]}$ | \overline{CE} LOW to Power-up | 0 | | ns |
| $t_{PD}^{[9]}$ | \overline{CE} HIGH to Power-down | | 10 | ns |
| t_{DBE} | Byte enable to data valid | | 5 | ns |
| t_{LZBE} | Byte enable to low-Z | 0 | | ns |
| t_{HZBE} | Byte disable to high-Z | | 5 | ns |
| Write Cycle^[10, 11] | | | | |
| t_{WC} | Write cycle time | 10 | | ns |
| t_{SCE} | \overline{CE} LOW to write end | 8 | | ns |
| t_{AW} | Address set-up to write end | 8 | | ns |
| t_{HA} | Address hold from write end | 0 | | ns |
| t_{SA} | Address set-up to write start | 0 | | ns |
| t_{PWE} | \overline{WE} pulse width | 7 | | ns |
| t_{SD} | Data set-up to write end | 5 | | ns |
| t_{HD} | Data hold from write end | 0 | | ns |
| t_{LZWE} | \overline{WE} HIGH to Low-Z ^[7] | 3 | | ns |
| t_{HZWE} | \overline{WE} LOW to High-Z ^[7, 8] | | 5 | ns |
| t_{BW} | Byte enable to end of write | 7 | | ns |

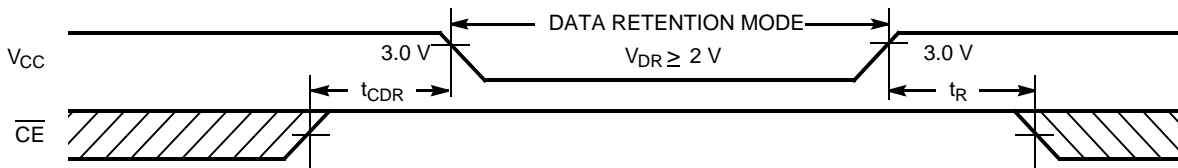
Notes

5. Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V.
6. t_{POWER} gives the minimum amount of time that the power supply should be at typical V_{CC} values until the first memory access can be performed
7. t_{HZOE} , t_{HZBE} , t_{HZCE} , and t_{HZWE} are specified with a load capacitance of 5 pF as in (c) of AC Test Loads. Transition is measured when the outputs enter a high impedance state.
8. At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE} , t_{HZOE} is less than t_{LZOE} , and t_{HZWE} is less than t_{LZWE} for any given device.
9. This parameter is guaranteed by design and is not tested.
10. The internal Write time of the memory is defined by the overlap of \overline{CE} LOW, \overline{WE} LOW and $\overline{BHE}/\overline{BLE}$ LOW. \overline{CE} , \overline{WE} and $\overline{BHE}/\overline{BLE}$ must be LOW to initiate a Write and the transition of these signals can terminate the Write. The input data set-up and hold timing should be referenced to the leading edge of the signal that terminates the Write.
11. The minimum write cycle time for Write Cycle 3 (WE controlled, \overline{OE} LOW) is the sum of t_{HZWE} and t_{SD} .

Data Retention Characteristics (Over the Operating Range)

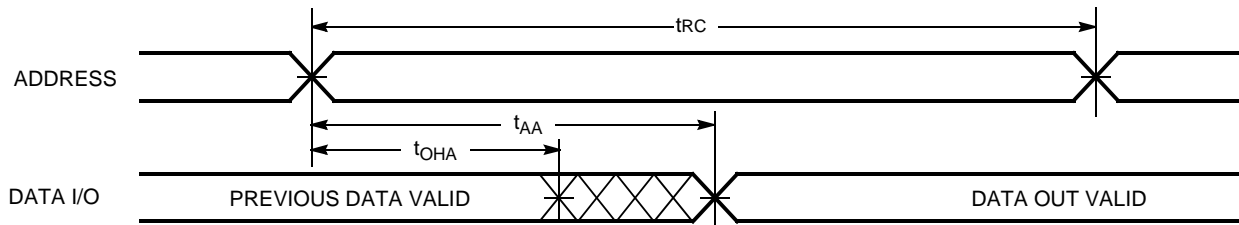
| Parameter | Description | Conditions | Min. | Max. | Unit |
|-----------------|--------------------------------------|--|----------|------|------|
| V_{DR} | V_{CC} | | 2.0 | | V |
| I_{CCDR} | Data retention current | $V_{CC} = V_{DR} = 2.0\text{ V}$, $\overline{CE} \geq V_{CC} - 0.3\text{ V}$, $V_{IN} \geq V_{CC} - 0.3\text{ V}$ or $V_{IN} \leq 0.3\text{ V}$ | | 3 | mA |
| $t_{CDR}^{[3]}$ | Chip deselect to data retention time | | 0 | | ns |
| $t_R^{[12]}$ | Operation recovery time | | t_{RC} | | ns |

Data Retention Waveform

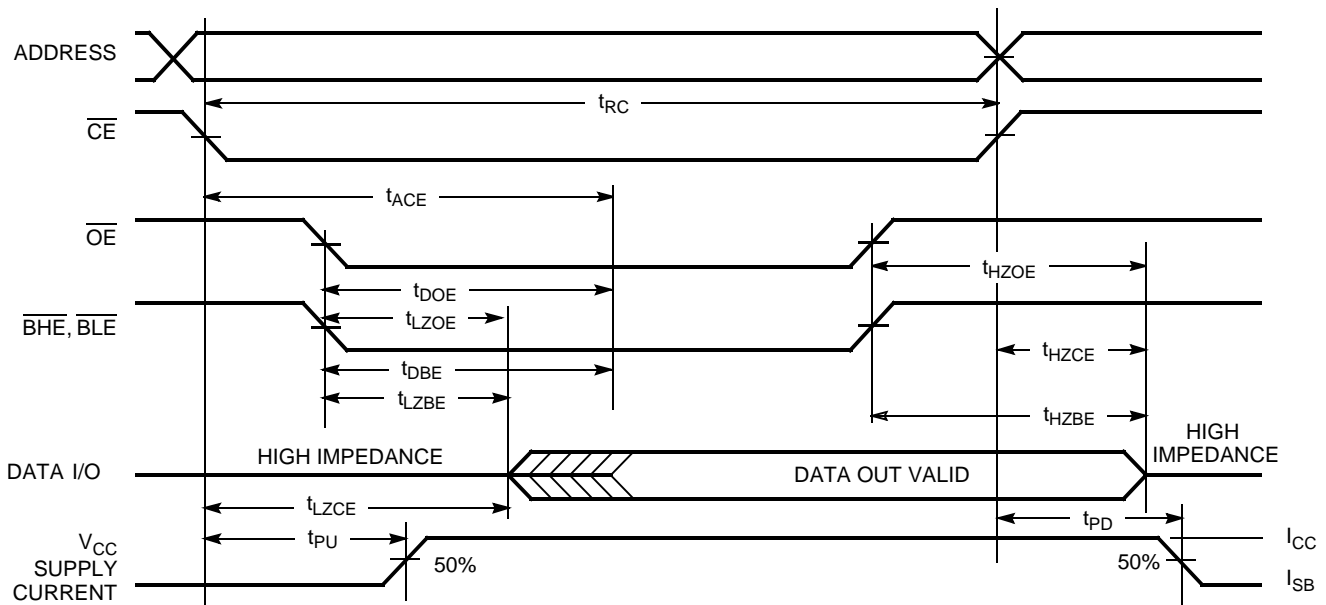


Switching Waveforms

Read Cycle No. 1 (Address Transition Controlled)^[13, 14]



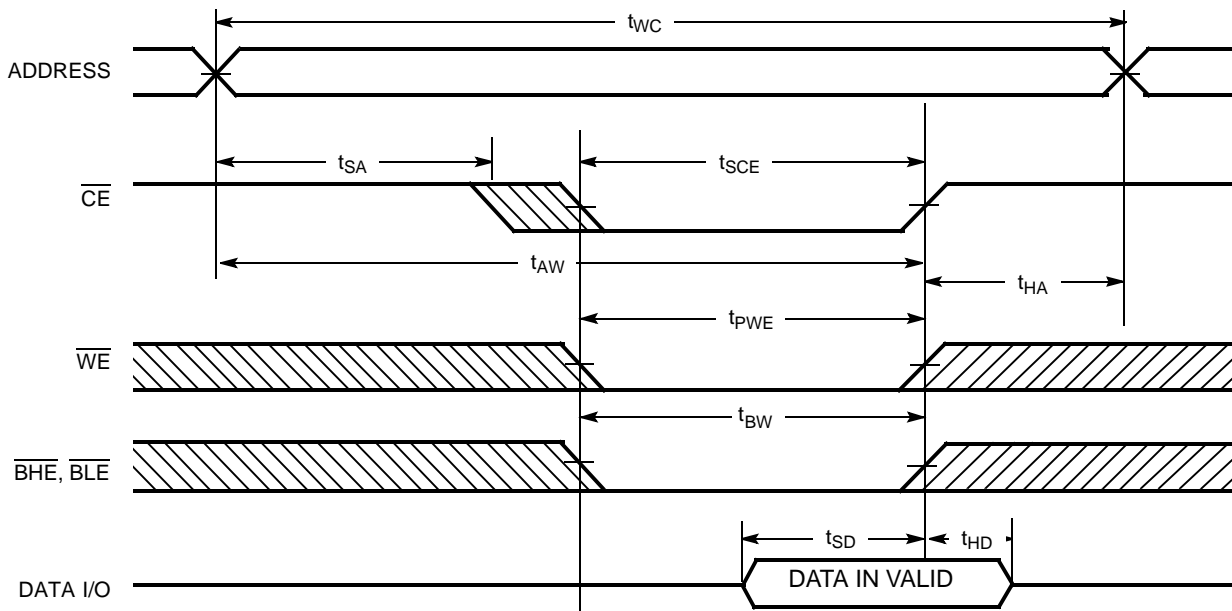
Read Cycle No. 2 (OE Controlled)^[14, 15]



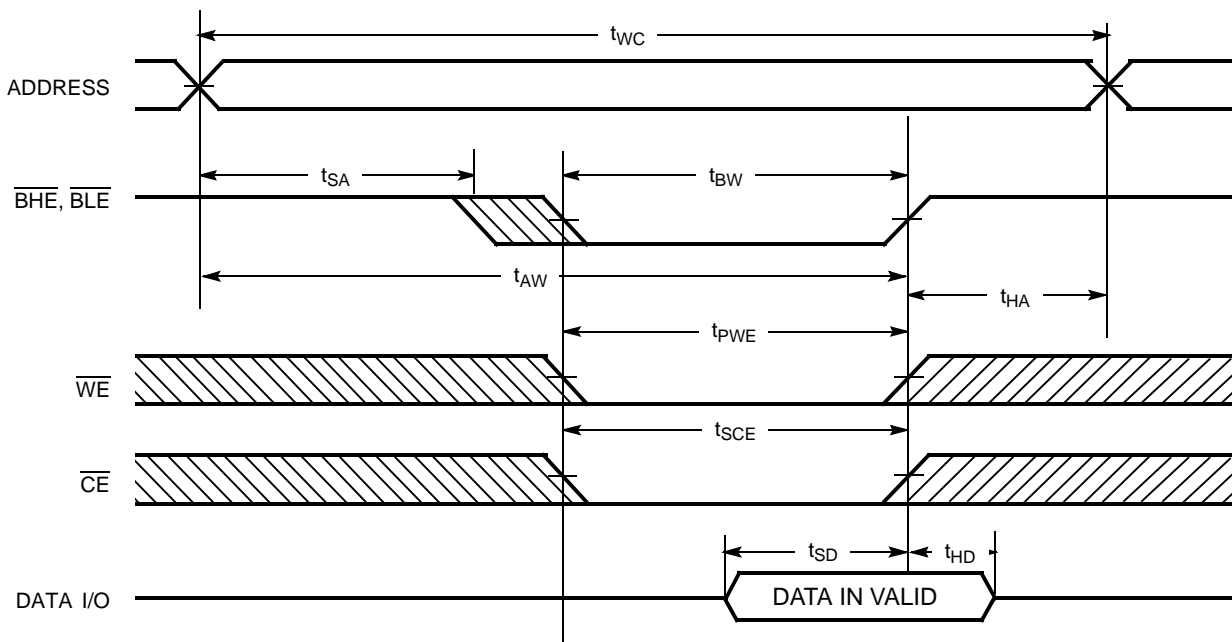
- Notes:**
- 12. Full device operation requires linear V_{CC} ramp from V_{DR} to $V_{CC(min)}$ $\geq 50\ \mu\text{s}$ or stable at $V_{CC(min)}$ $\geq 50\ \mu\text{s}$.
 - 13. Device is continuously selected. \overline{OE} , \overline{CE} , \overline{BHE} and/or $\overline{BLE} = V_{IL}$.
 - 14. \overline{WE} is HIGH for Read cycle.
 - 15. Address valid prior to or coincident with \overline{CE} transition LOW.

Switching Waveforms (continued)

Write Cycle No. 1 ($\overline{\text{CE}}$ Controlled)^[16, 17]



Write Cycle No. 2 ($\overline{\text{BLE}}$ or $\overline{\text{BHE}}$ Controlled)



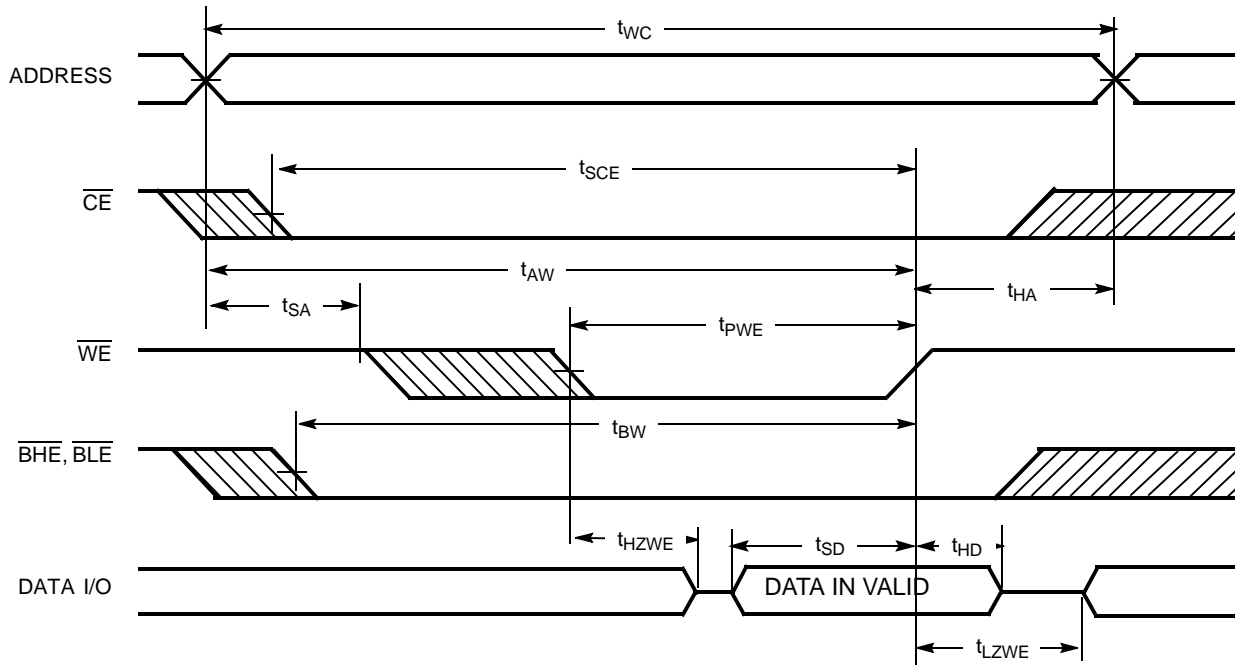
Notes:

16. Data I/O is high impedance if $\overline{\text{OE}}$ or $\overline{\text{BHE}}$ and/or $\overline{\text{BLE}} = V_{IH}$.

17. If $\overline{\text{CE}}$ goes HIGH simultaneously with $\overline{\text{WE}}$ going HIGH, the output remains in a high-impedance state.

Switching Waveforms (continued)

Write Cycle No. 3 (\overline{WE} Controlled, \overline{OE} LOW)



Truth Table

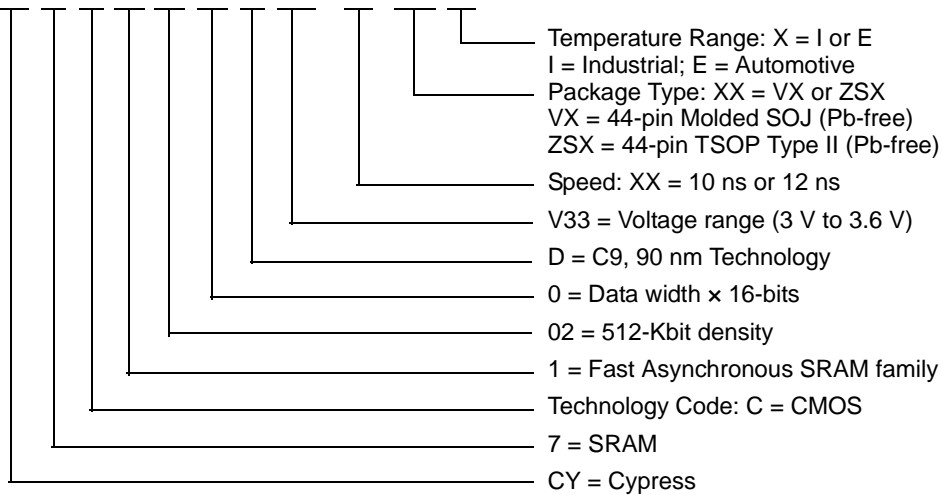
| \overline{CE} | \overline{OE} | \overline{WE} | \overline{BLE} | \overline{BHE} | I/O ₀ -I/O ₇ | I/O ₈ -I/O ₁₅ | Mode | Power |
|-----------------|-----------------|-----------------|------------------|------------------|------------------------------------|-------------------------------------|----------------------------|----------------------|
| H | X | X | X | X | High-Z | High-Z | Power-down | Standby (I_{SB}) |
| L | L | H | L | L | Data Out | Data Out | Read—All bits | Active (I_{CC}) |
| | | | L | H | Data Out | High-Z | Read—Lower bits only | Active (I_{CC}) |
| | | | H | L | High-Z | Data Out | Read—Upper bits only | Active (I_{CC}) |
| L | X | L | L | L | Data In | Data In | Write—All bits | Active (I_{CC}) |
| | | | L | H | Data In | High-Z | Write—Lower bits only | Active (I_{CC}) |
| | | | H | L | High-Z | Data In | Write—Upper bits only | Active (I_{CC}) |
| L | H | H | X | X | High-Z | High-Z | Selected, Outputs Disabled | Active (I_{CC}) |
| L | X | X | H | H | High-Z | High-Z | Selected, Outputs Disabled | Active (I_{CC}) |

Ordering Information

| Speed (ns) | Ordering Code | Package Name | Package Type | Operating Range |
|------------|---------------------|--------------|-------------------------------|-----------------|
| 10 | CY7C1020DV33-10ZSXI | 51-85087 | 44-pin TSOP Type II (Pb-free) | Industrial |

Ordering Code Definitions

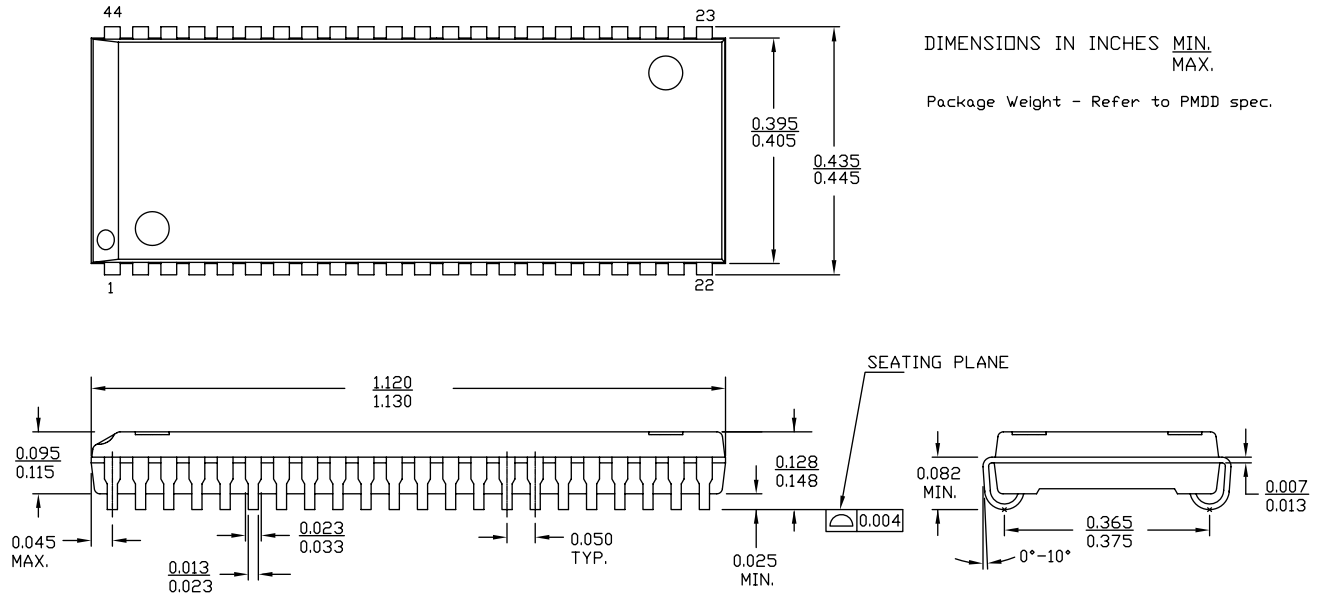
CY 7 C 1 02 0 D V33 - XX XX X



Shaded areas contain advance information. Please contact your local Cypress sales representative for availability of these parts.

Package Diagrams

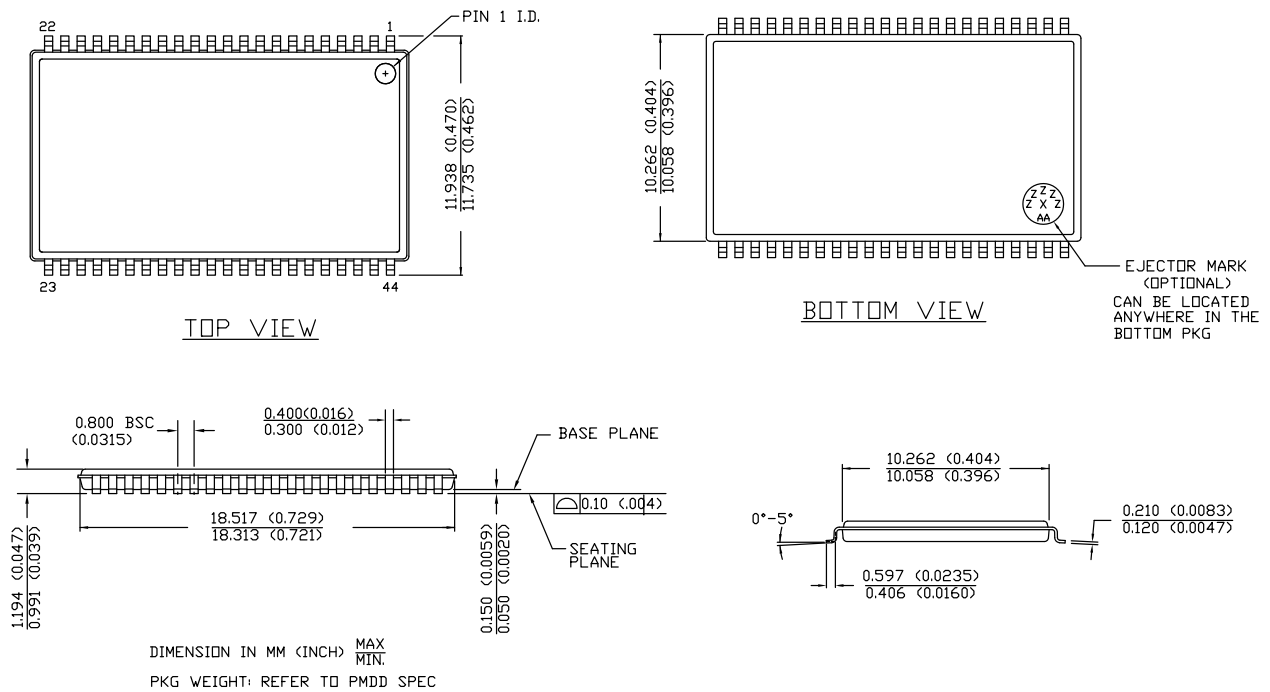
Figure 1. 44-pin (400-Mil) Molded SOJ (51-85082)



51-85082 *E

Package Diagrams (continued)

Figure 2. 44-Pin Thin Small Outline Package Type II (51-85087)



51-85087 *E

Acronyms

| Acronym | Description |
|-------------------------|---|
| $\overline{\text{BHE}}$ | byte high enable |
| $\overline{\text{BLE}}$ | byte low enable |
| $\overline{\text{CE}}$ | chip enable |
| CMOS | complementary metal oxide semiconductor |
| I/O | input/output |
| $\overline{\text{OE}}$ | output enable |
| SRAM | static random access memory |
| TSOP | thin small outline package |
| $\overline{\text{WE}}$ | write enable |

Document Conventions

Units of Measure

| Symbol | Unit of Measure |
|--------|-----------------|
| °C | degrees Celsius |
| μA | microamperes |
| mA | milliamperes |
| MHz | megahertz |
| ns | nanoseconds |
| pF | picofarads |
| V | volts |
| Ω | ohms |
| W | watts |

Document History Page

| Document Title: CY7C1020DV33, 512 K (32 K x 16) Static RAM | | | | |
|--|---------|------------|-----------------|--|
| Document Number: 38-05461 | | | | |
| REV. | ECN NO. | Issue Date | Orig. of Change | Description of Change |
| ** | 201560 | See ECN | SWI | Advance Information data sheet for C9 IPP |
| *A | 233695 | See ECN | RKF | DC parameters modified as per EROS (Spec # 01-02165) Pb-free Offering in Ordering Information |
| *B | 262950 | See ECN | RKF | Changed I/O ₁ – I/O ₁₆ to I/O ₀ – I/O ₁₅ Added Data Retention Characteristics table Added T _{power} spec in Switching Characteristics table Added 44-SOJ package diagram Shaded Ordering Information |
| *C | 307596 | See ECN | RKF | Reduced Speed bins to –8 and –10 ns |
| *D | 560995 | See ECN | VKN | Converted from Preliminary to Final Removed Commercial operating range Removed 8 ns speed bin Added Automotive information Added I _{CC} values for the frequencies 83MHz, 66MHz and 40MHz Updated Thermal Resistance table Updated Ordering Information table Changed Overshoot spec from V _{CC} +2 V to V _{CC} +1 V in footnote #4 |
| *E | 2898399 | 03/24/2010 | AJU | Updated Package Diagrams |
| *F | 3109992 | 12/14/2010 | AJU | Added Ordering Code Definitions . |
| *G | 3424450 | 10/28/2011 | TAVA | Updated footnotes Updated Selection Guide , Operating Range , Electrical Characteristics Over the Operating Range , Switching Characteristics Over the Operating Range ^[5] , Data Retention Characteristics (Over the Operating Range) , Switching Waveforms , and Ordering Information . Updated Package Diagrams Added Acronyms , and Document Conventions |
| *H | 3861347 | 01/08/2013 | TAVA | Updated Ordering Information (Updated part numbers). Updated Package Diagrams : spec 51-85082 – Changed revision from *D to *E. spec 51-85087 – Changed revision from *D to *E. |
| *I | 4574311 | 11/19/2014 | TAVA | Added related documentation hyperlink in page 1. Added note 11 in Switching Characteristics Over the Operating Range ^[5] . Added note reference in the Switching Characteristics table. |

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